## NSN 5961-01-375-0809

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-375-0809 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** 1.1 millimeters **Overall Width:** Between 1.2 millimeters and 1.4 millimeters **End Application:** 6625-01-286-3566 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Cubic Measure:** 4.62 cubic meters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 milliamperes all primaries preset **Power Rating Per Characteristic:** 200.0 milliwatts any acceptable preset **Capacitance Rating In Picofarads:** 1.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: